



ZXTP749F

#### 25V PNP LOW SATURATION TRANSISTOR IN SOT23

#### **Features**

- BV<sub>CEO</sub> > -25V
- BV<sub>CEO</sub> > -35V forward blocking voltage
- I<sub>C</sub> = -3A Continuous Collector Current
- Low Saturation Voltage, V<sub>CE(SAT)</sub> < -150mV @ -1A.</li>
- $R_{CE(sat)} = 87m\Omega$  for a low equivalent on-resistance
- 725mW power dissipation
- h<sub>FE</sub> characterised up to -6A for high current gain hold-up
- Complementary NPN Type: ZXTN649F
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

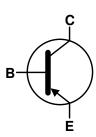
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads
- Solderable per MIL-STD-202, Method 208 (3)
- Weight 0.008 grams (Approximate)

### **Application**

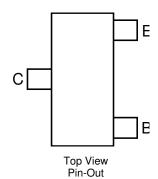
- MOSFET Gate Drivers
- Power Switching in Automotive and Industrial Applications
- Motor Drive and Control







Device Symbol



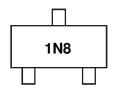
#### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP749FTA	1N8	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



1N8 = Product Type Marking Code



# Absolute Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-35	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-25	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-3	A
Peak Pulse Current	Ісм	-6	Α
Base Current	I <sub>B</sub>	-500	mA
Peak Pulse Current	I <sub>BM</sub>	-2	Α

#### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	$P_{D}$	725	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	172	°C/W
Thermal Resistance, Junction to Leads (Note 6)	$R_{ heta JL}$	79	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## ESD Ratings (Note 7)

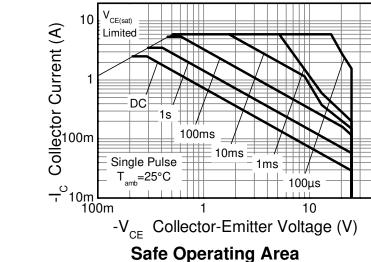
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗА
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

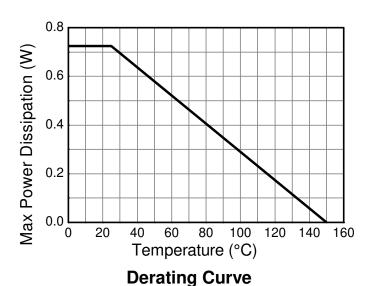
Notes:

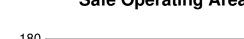
- 5. For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1 oz. copper, in still air conditions; the device is measured when operating in a steady-state condition.
  6. Thermal resistance from junction to solder-point (at the end of the collector lead).
  7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

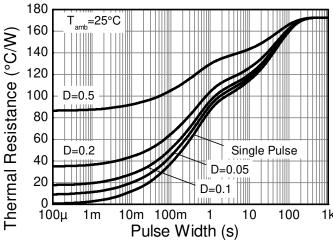


### **Thermal Characteristics and Derating information**









Single Pulse T anto =25°C

10m 100m

100μ

**Transient Thermal Impedance** 

**Pulse Power Dissipation** 

Pulse Width (s)

10

100



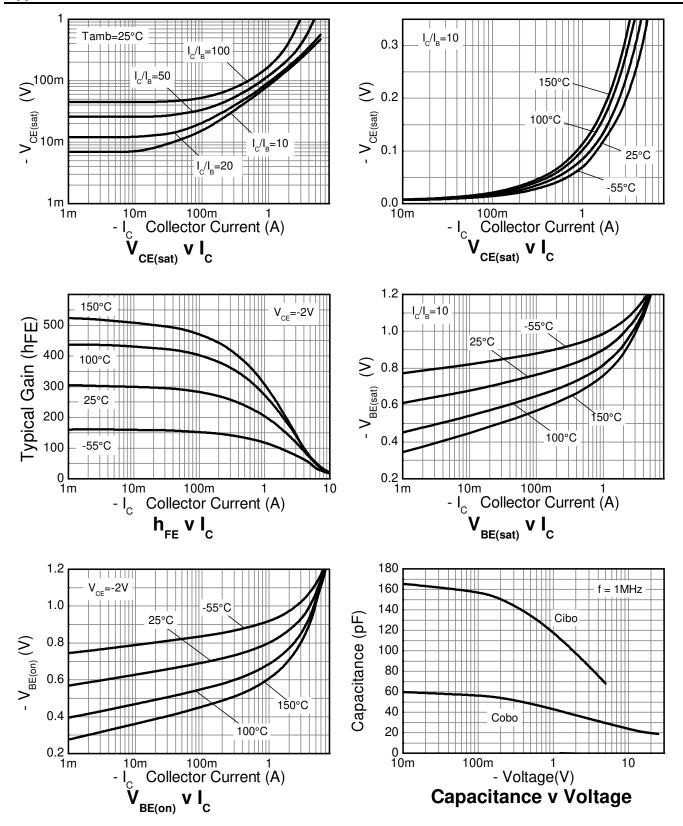
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_CBO$	-35	-60	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	-25	-40	-	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.4	-	V	$I_E = -100 \mu A$
Collector Cutoff Current	Ісво	-	<1	-50	nA	V <sub>CB</sub> = -28V
Collector Guton Current				-0.5	μΑ	$V_{CB} = -28V, T_A = +100^{\circ}C$
Emitter Cutoff Current	I <sub>EBO</sub>	-	<1	-50	nA	$V_{EB} = -5.6V$
		200	320	500		$I_C = -100 \text{mA}, V_{CE} = -2V$
Static Forward Current Transfer Ratio (Note 8)	h <sub>FE</sub>	130	230	-	_	$I_C = -1A$ , $V_{CE} = -2V$
Static Forward Gurrent Transfer Hatle (Note 6)	IIFE .	100	180	-		$I_{C} = -2A$ , $V_{CE} = -2V$
		25	50	-		$I_C = -6A, V_{CE} = -2V$
Collector-Emitter Saturation Voltage (Note 8)	V <sub>CE(sat)</sub>	-	-85	-150	mV	$I_C = -1A$ , $I_B = -100mA$
Collector-Entitler Saturation Voltage (Note 6)		-	-229	-350	111 V	$I_C = -3A$ , $I_B = -300mA$
Base-Emitter Turn-On Voltage (Note 8)	$V_{BE(on)}$	-	-786	-850	mV	$I_C = -1A, V_{CE} = -2V$
Base-Emitter Saturation Voltage (Note 8)	$V_{BE(sat)}$	-	-895	-1,000	mV	$I_C = -1A$ , $I_B = -100mA$

Notes: 8. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



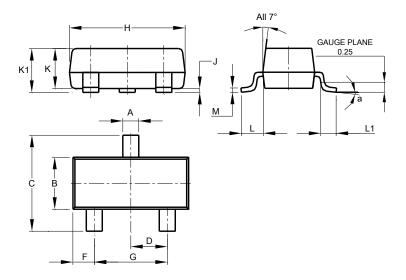
### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





## **Package Outline Dimensions**

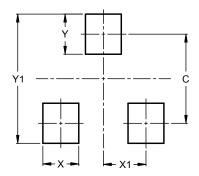
Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
C	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
7	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
٦	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	0°	8°			
All Dimensions in mm					

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
С	2.0			
X	0.8			
X1	1.35			
Υ	0.9			
V1	2.0			



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